



DMN2009UFDF

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
	9mΩ @ V <sub>GS</sub> = 4.5V	12.8A
20V	$13m\Omega @ V_{GS} = 2.5V$	10.7A

### Description

This new generation MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

## Applications

- General purpose interfacing switches
- Power management functions

### 20V N-CHANNEL ENHANCEMENT MODE MOSFET

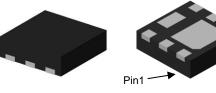
### **Features**

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm<sup>2</sup>
- Low Gate Threshold Voltage
- Low On-Resistance .
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

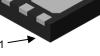
### **Mechanical Data**

- Package: U-DFN2020-6
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.007 grams (Approximate)

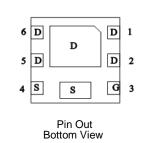
U-DFN2020-6 (Type F)

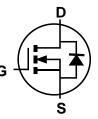


Top View



Bottom View





Equivalent Circuit

### Ordering Information (Note 4)

Part Number	Paakaga	Packing			
Fait Nulliber	Package	Qty.	Carrier		
DMN2009UFDF-7	U-DFN2020-6 (Type F)	3,000	Tape & Reel		
DMN2009UFDF-13	U-DFN2020-6 (Type F)	10,000	Tape & Reel		

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Notes:



# **Marking Information**

### Site 1



M9 = Product Type Marking Code  $\begin{array}{l} \text{YM} = \text{Product Type Marking Courses} \\ \text{YM} = \text{Date Code Marking} \\ \text{Y} = \text{Year (ex: J = 2022)} \\ \text{M} = \text{Month (ex: 9 = September)} \end{array}$ 

Date Code Kev

Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н	-	J	К	L	М	Ν	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



M9 = Product Type Marking Code

YWX = Date Code Marking

Y = Year (ex: 2 = 2022)W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key												
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	0	1	2	3	4	5	6	7	8	9	0	1
Week		1	-26			27	-52			į	53	
Code		A	N-Z			a-z z			Z			
Internal Code	Sur	ו ו	Mon		Tue	w	ed	Thu		Fri		Sat
Code	Т		U		V	V	V	Х		Y		Z



# Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	V			
Gate-Source Voltage	Vgss	±12	V		
Continuous Drain Current (Note 5) $V_{GS} = 4.5V$	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	12.8 10.3	А
Maximum Body Diode Continuous Current (Note 5)			ls	2.5	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1	%)		Ідм	85	А
Pulsed Body Diode Continuous Current (380µs Pul	= 1%)	lsм	85	А	
Avalanche Current (Note 6) L = 0.1mH		las	15.6	А	
Avalanche Energy (Note 6) L = 0.1mH			Eas	12.1	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 7)	T <sub>A</sub> = +25°C	PD	1.3	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	RθJA	96.8	°C/W
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	1.7	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	56	°C/W
Thermal Resistance, Junction to Case (Note 5)		Rejc	9.6	C/VV
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

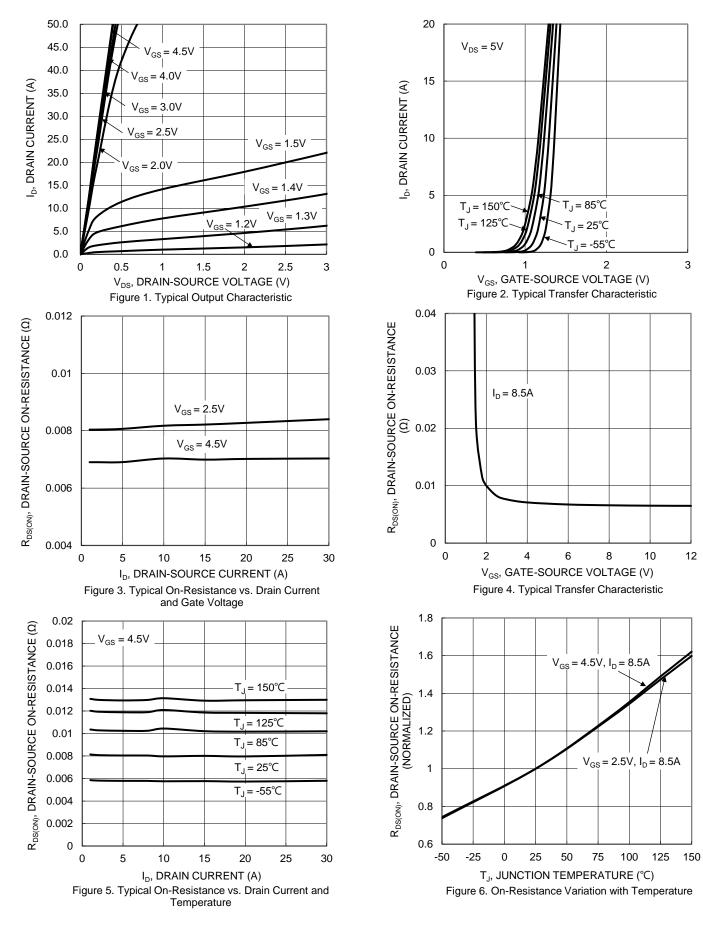
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BVDSS	20	_	_	V	$V_{GS} = 0V, I_{D} = 250 \mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	IDSS		_	1	μA	$V_{DS} = 16V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	Vgs(th)	0.5		1.4	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Descent		7	9	mΩ	$V_{GS} = 4.5V, I_D = 8.5A$
Static Drain-Source On-Resistance	Rds(on)		9.2	13	11122	$V_{GS} = 2.5V, I_D = 8.5A$
Diode Forward Voltage	Vsd	_	0.7	1.2	V	VGS = 0V, IS = 8.5A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		1083	—	pF	
Output Capacitance	Coss		165	—	pF	− V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V − f = 1.0MHz
Reverse Transfer Capacitance	Crss		110	—	pF	1 = 1:00012
Gate Resistance	Rg		5.5	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		12.7	—	nC	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		27.9	—	nC	
Gate-Source Charge	Q <sub>gs</sub>	_	2.3	_	nC	VDS = 10V, ID = 8.5A
Gate-Drain Charge	Qgd	_	1.4	_	nC	7
Turn-On Delay Time	t <sub>D(ON)</sub>		7	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	2.7	_	ns	V <sub>DS</sub> = 10V, I <sub>D</sub> = 8.5A
Turn-Off Delay Time	tD(OFF)		31.9	_	ns	V <sub>GS</sub> = 4.5V, R <sub>G</sub> = 1.8Ω
Turn-Off Fall Time	tF		14.6	_	ns	7

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. Notes:

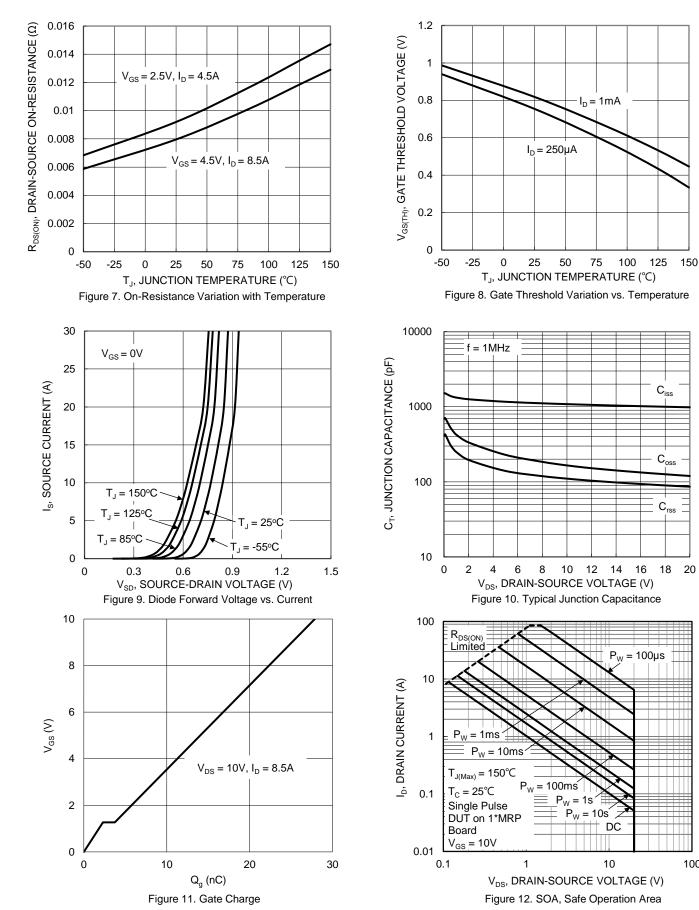
5. Device mounted on FR-4 substrate PC board, 202 copper, with remaining bias to bottom layer 6. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}$ C. 7. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. 8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to product testing.



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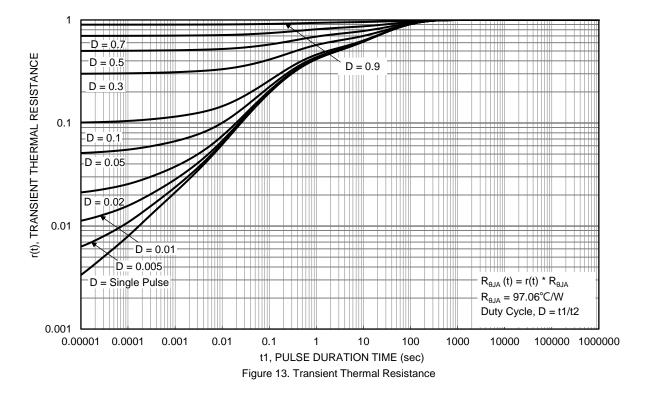




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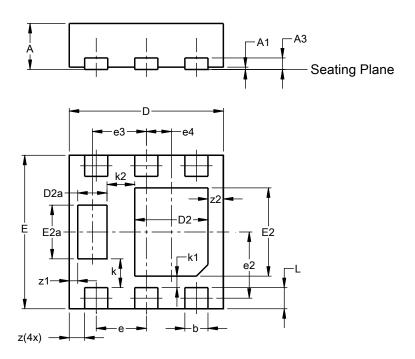






## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



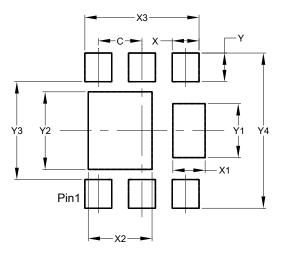
U-DFN2020-6	(Type F)
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	U-DFN2020-6						
	(Тур	be F)					
Dim	Min	Max	Тур				
Α	0.57	0.63	0.60				
A1	0.00	0.05	0.03				
A3	-	-	0.15				
b	0.25	0.35	0.30				
D	1.95	2.05	2.00				
D2	0.85	1.05	0.95				
D2a	0.33	0.43	0.38				
Е	1.95	2.05	2.00				
E2	1.05	1.25	1.15				
E2a	0.65	0.75	0.70				
е	0.65 BSC						
e2	C	).863 BS	SC				
e3		0.70 BS	С				
e4	C	).325 BS	SC				
k		0.37 BS	С				
k1		0.15 BS	С				
k2		0.36 BS	С				
L	0.225	0.325	0.275				
z		0.20 BS					
z1	C	).110 BS	SC				
z2		0.20 BS	-				
Ali C	Dimens	ions in	mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### U-DFN2020-6 (Type F)



Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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